NSN 5961-01-433-8841

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-433-8841 **Inclosure Material:** Glass **Overall Length:** Between 0.185 inches and 0.210 inches **Terminal Length:** Between 0.010 inches and 0.020 inches **Mounting Method: Terminal Terminal Circle Diameter:** Between 0.092 inches and 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 200.0 breakdown voltage, instantaneous **Current Rating Per Characteristic:** 10.00 microamperes collector current, dc peak **Power Rating Per Characteristic:** 1.0 watts any acceptable preset **Capacitance Rating In Picofarads:** 1.5 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 electron tube base Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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